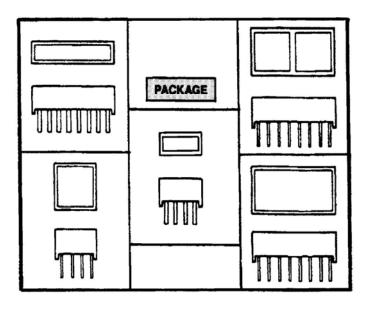


## HIGH EFFICIENCY RED HLMP-2300/2600 SERIES YELLOW HLMP-2400/2700 SERIES HIGH EFFICIENCY GREEN HLMP-2500/2800 SERIES



## DESCRIPTION

These LED Light Bar series are bright, large emitting area, rectangular devices that are designed for backlighting legend/message annunciators.

These devices are offered in single-in-line and dual-in-line packages that contain single or segmented light-emitting area. Each package style is offered in High Efficiency Red, Yellow, or Green emission color.

## FEATURES

- Large area, uniform, bright light-emitting surfaces
- Select from six package styles
- Choice of three colors
- Categorized for intensity and color
- X-Y stackable
- Easily driven with I.C.s
- Alternate source for popular backlighting components

MODEL	NUMBERS			
PART NO.	COLOR	DESCRIPTION	PACKAGE	PIN OUT
HLMP-2300 HLMP-2400 HLMP-2500	High Efficiency Red Yellow High Efficiency Green	2 LED Single-in-line 0.35 in.×0.15 in. Area	A	А
HLMP-2350 HLMP-2450 HLMP-2550	High Efficiency Red Yellow High Efficiency Green	4 LED Single-in-line 0.75 in.×0.15 in. Area	в	в
HLMP-2655 HLMP-2755 HLMP-2855	High Efficiency Red Yellow High Efficiency Green	4 LED Dual-in-line 0.35 in.×0.35 in. Area	с	с
HLMP-2670 HLMP-2770 HLMP-2870	High Efficiency Red Yellow High Efficiency Green	Dual 0.35 in.×0.35 in. Area Dual-in-line package	D	D
HLMP-2685 HLMP-2785 HLMP-2885	High Efficiency Red Yellow High Efficiency Green	8 LED 0.35 in.×0.75 in. Area Dual-in-line package	E	D



PARAMETER			HLMP					TEST	
		SYMBOL	-2300	-2350	-2655	-2670	-2685	UNIT	CONDITIONS
Luminous	min.		6.0	13	13	13	22	mcd	I <sub>F</sub> =20 mA
Intensity	typ.	lv.	23	45	43	45	80	mcd	I <sub>F</sub> =20 mA
intensity	typ.		30	50	50	50	100	mcd	I <sub>r</sub> =60 mA pK, 1:3 D.F
Forward	max.	VF	2.6	2.6	2.6	2.6	2.6	V	I <sub>r</sub> =20 mA
voltage	typ.	VF	2.0	2.0	2.0	2.0	2.0	v	F-20 MA
Peak wavelength	typ.	$\lambda_{p}$	630	630	630	630	630	nm	
Dominant wavelength	typ.	$\lambda_{\sigma}$	626	626	626	626	626	nm	
Capacitance	typ.	С	45	45	45	45	45	pF	V <sub>F</sub> =0, f=1 MHz
Reverse voltage	min.	V <sub>R</sub>	6	6	6	6	6	v	I <sub>R</sub> =100 μA
Thermal resistance	typ.	θ <sub>JL</sub>	150	150	150	150	150	°C/W/ LED chip	

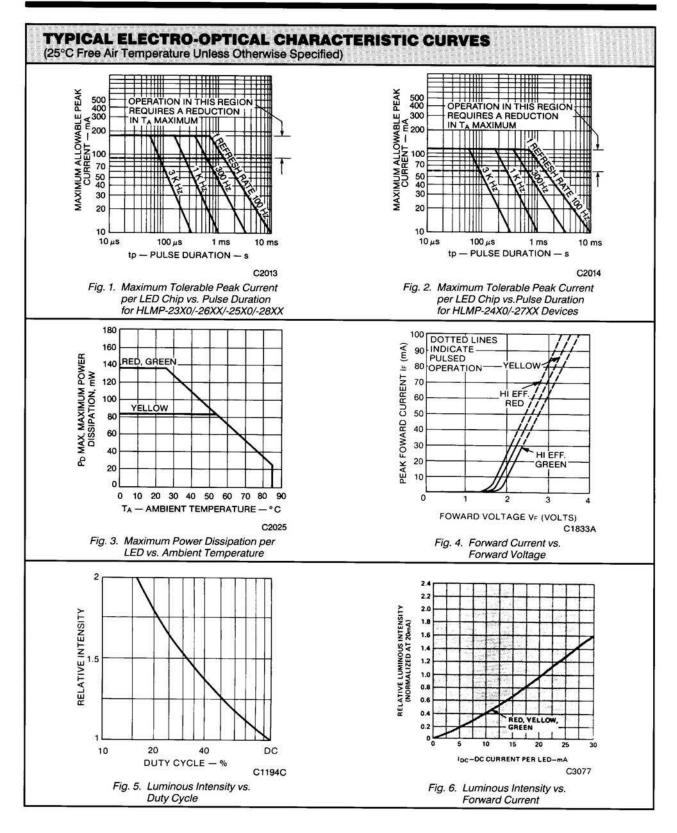
## ELECTRO-OPTICAL CHARACTERISTICS (T\_=25°C)

			HLMP						TEST
PARAMETER		SYMBOL	-2400	-2450	-2755	-2770	-2785	UNIT	CONDITIONS
Luminous	min.		6	13	13	13	26	mcd	I <sub>F</sub> =20 mA
	typ. I <sub>v</sub>	l <sub>v</sub>	20	38	35	35	70	mcd	$l_F = 20 \text{ mA}$
Intensity	typ.		33	60	60	60	115	mcd	IF=60 mA pK, 1:3 D.F.
Forward	orward max.	VF	2.6	2.6	2.6	2.6	2.6	V	I <sub>F</sub> =20 mA
voltage	typ.	VF	2.1	2.1	2.1	2.1	2.1	v	
Peak wavelength	typ.	$\lambda_{p}$	585	585	585	585	585	nm	
Dominant wavelength	typ.	$\lambda_{d}$	588	588	588	588	588	nm	
Capacitance	typ.	С	35	35	35	35	35	pF	V <sub>F</sub> =0, f=1 MHz
Reverse voltage	min.	V <sub>R</sub>	6	6	6	6	6	v	l <sub>s</sub> =100 μA
Thermal resistance	typ.	θ <sub>JL</sub>	150	150	150	150	150	°C/W/ LED chip	

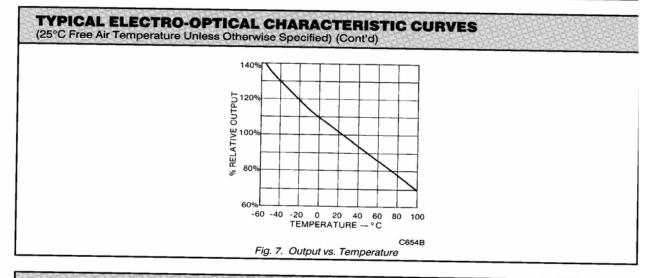
## ELECTRO-OPTICAL CHARACTERISTICS (T\_=25°C)

			HLMP						TEST
PARAMETER		SYMBOL	-2500	-2550	-2855	-2870	-2885	UNIT	CONDITIONS
Luminous	min.	100	5	11	11	11	22	mcd	I⊧=20 mA
	typ.	l <sub>v</sub>	25	50	50	50	100	mcd	$I_F = 20 \text{ mA}$
Intensity	typ.		38	75	75	75	150	mcd	I <sub>F</sub> =60 mA pK, 1:3 D.F
Forward	max.	VF	2.6	2.6	2.6	2.6	2.6	v	I <sub>F</sub> =20 mA
voltage	typ.	VF	2.2	2.2	2.2	2.2	2.2	v	
Peak wavelength	typ.	$\lambda_p$	565	565	565	565	565	nm	
Dominant wavelength	typ.	$\lambda_{d}$	567	567	567	567	567	nm	
Capacitance	typ.	С	40	40	40	40	40	pF	$V_{F}=0$ , f=1 MHz
Reverse voltage	min.	V <sub>R</sub>	6	6	6	6	6	v	I <sub>8</sub> =100 μA
Thermal resistance	typ.	θ <sub>JL</sub>	150	150	150	150	150	°C/W/ LED chip	

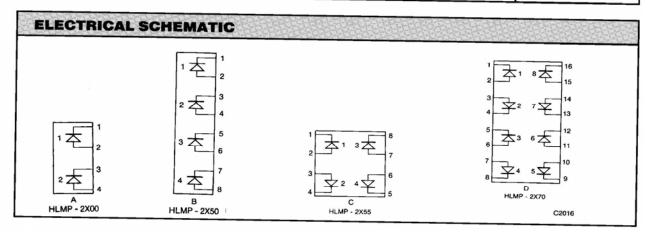








PIN	ELECTRICAL CONNECTION									
	HLMP-2X00	HLMP-2X50	HLMP-2X55	HLMP-2X70/-2X85						
1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16	1 Cathode 1 Anode 2 Cathode 2 Anode	1 Cathode 1 Anode 2 Cathode 3 Cathode 3 Anode 4 Cathode 4 Anode	1 Cathode 1 Anode 2 Anode 2 Cathode 3 Cathode 3 Anode 4 Anode 4 Cathode	1 Cathode 1 Anode 2 Anode 2 Cathode 3 Cathode 3 Anode 4 Anode 4 Cathode 5 Cathode 5 Anode 6 Anode 6 Cathode 7 Cathode 7 Cathode 8 Anode 8 Anode 8 Cathode						





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  - device or system whose failure to perform can be or (b) reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.